NSN 5961-01-372-8863

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-372-8863 **Inclosure Material:** Plastic **Overall Length:** 0.240 inches **Terminal Length:** 0.200 inches **Overall Diameter:** 0.500 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 45.0 breakdown voltage, collector-to-base, emitter open all transistor and 5.0 breakdown voltage, emitter-to-base, collector open all transistor and 45.0 breakdown voltage, collector-to-emitter, base open all transistor **Current Rating Per Characteristic:** 25.00 milliamperes all primaries all transistor **Power Rating Per Characteristic:** 640.0 milliwatts any acceptable preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 85.0 degrees celsius ambient air **Test Data Document:** 98750-8949408 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 8 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No